

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
100V	5.0Ω@10V	0.2A
	5.5Ω@4.5V	

Feature

- Advanced trench process technology
- Voltage Controlled Small Signal Switch

Application

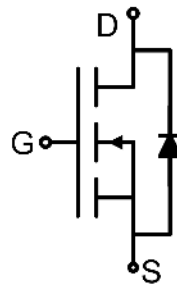
- Small Servo Motor Controls
- Power MOSFET Gate Drivers
- Switching Application

Package

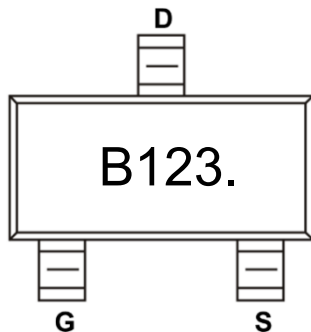


SOT-23

Circuit diagram



Marking



Absolute maximum ratings (Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	100	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current	I_D	0.2	A
Pulsed Drain Current	I_{DM}	0.8	A
Power Dissipation	P_D	0.35	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	357	°C/W
Junction Temperature	T_J	150	°C
Storage Temperature	T_{STG}	-55 ~ +150	°C

Electrical characteristics (T_A=25 °C, unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	100			V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 100V, V_{GS} = 0V$			1	μA
Gate-body leakage current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			±100	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	1.0		2.5	V
Drain-source on-resistance ¹⁾	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 0.2A$			5.0	Ω
		$V_{GS} = 4.5V, I_D = 0.175A$			5.5	
Dynamic characteristics²⁾						
Input Capacitance	C_{iss}	$V_{DS} = 50V, V_{GS} = 0V, f = 1MHz$		14		pF
Output Capacitance	C_{oss}			10		
Reverse Transfer Capacitance	C_{rss}			5		
Total Gate Charge	Q_g	$V_{DS} = 50V, V_{GS} = 10V, I_D = 0.2A$		1.8		nC
Turn-on delay time	$t_{d(on)}$	$V_{DD} = 50V, V_{GS} = 10V, I_D = 0.2A, R_{GEN} = 6\Omega$		1.7		nS
Turn-on rise time	t_r			9		
Turn-off delay time	$t_{d(off)}$			17		
Turn-off fall time	t_f			7		
Source-Drain Diode characteristics						
Diode Forward Current ¹⁾	I_S				0.2	A
Diode Forward voltage	V_{DS}	$V_{GS} = 0V, I_S = 0.2A$			1.2	V

Notes:

- 1) Pulse Test: Pulse Width < 300μs, Duty Cycle ≤2%.
- 2) Guaranteed by design, not subject to production testing.

Typical Characteristics

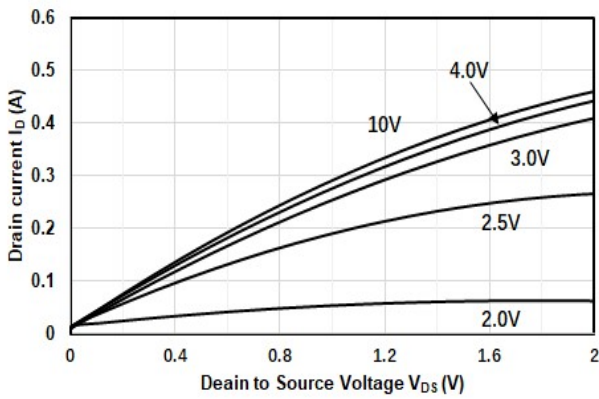


Figure1. Output Characteristics

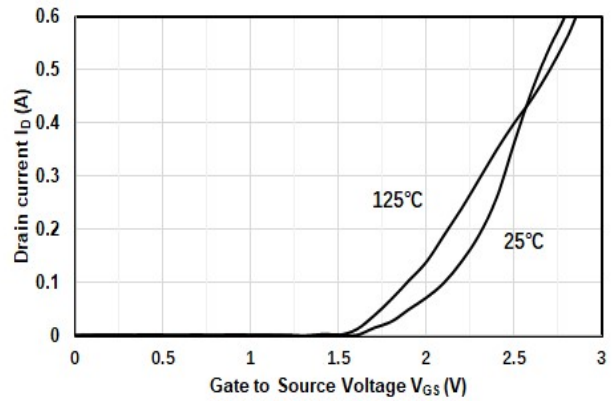


Figure2. Transfer Characteristics

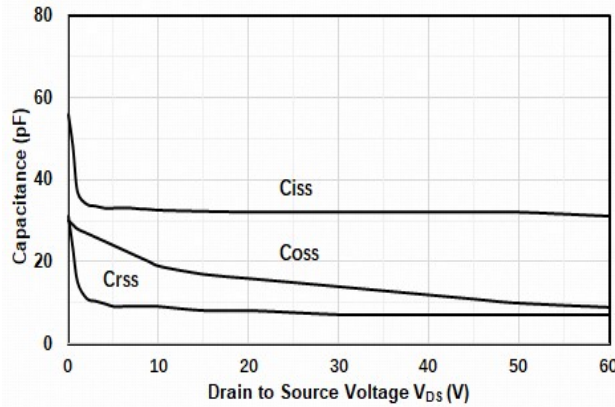


Figure3. Capacitance Characteristics

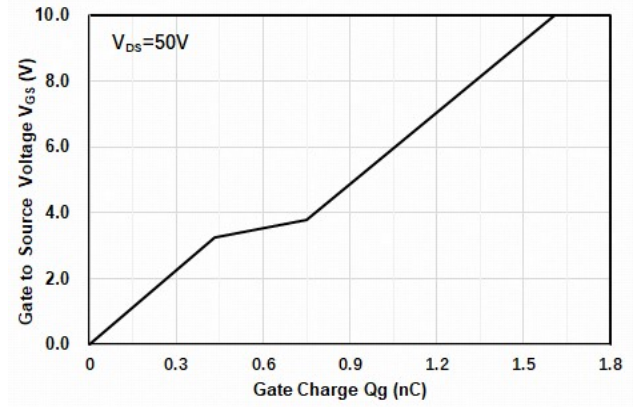


Figure4. Gate Charge

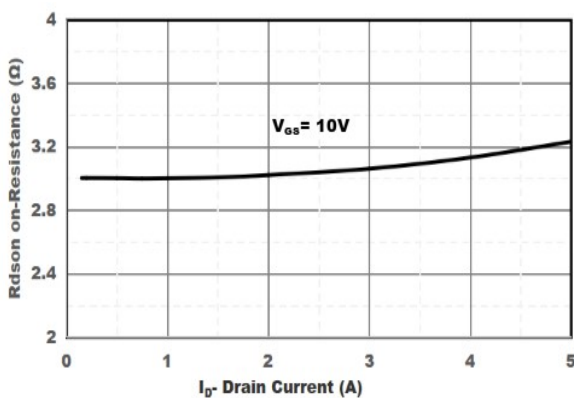


Figure5. Drain-Source on Resistance

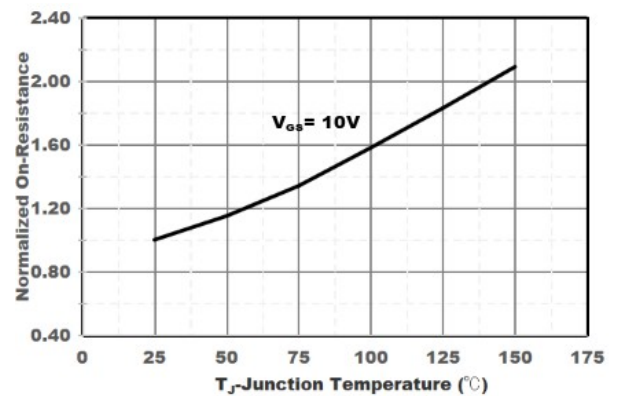


Figure6. Drain-Source on Resistance

Typical Characteristics

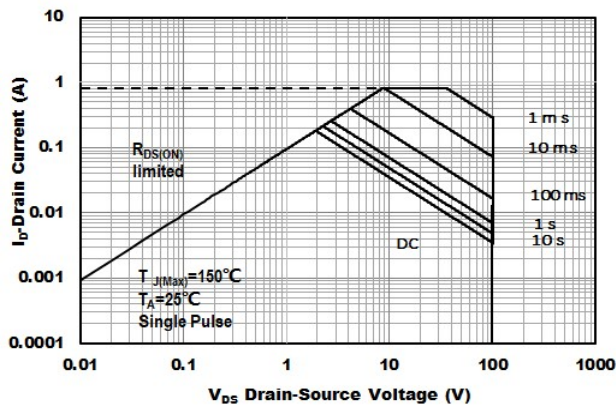


Figure7. Safe Operation Area

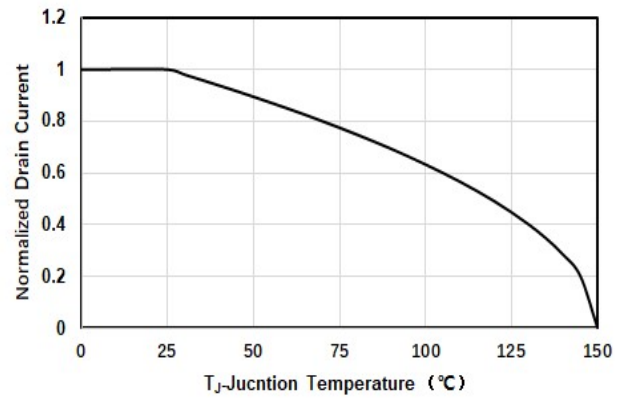
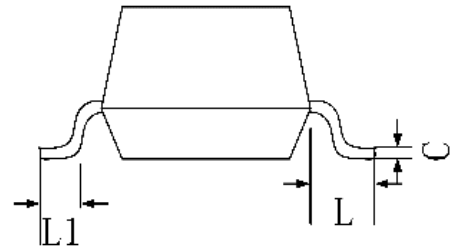
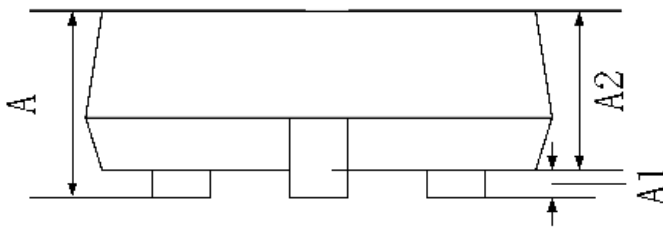
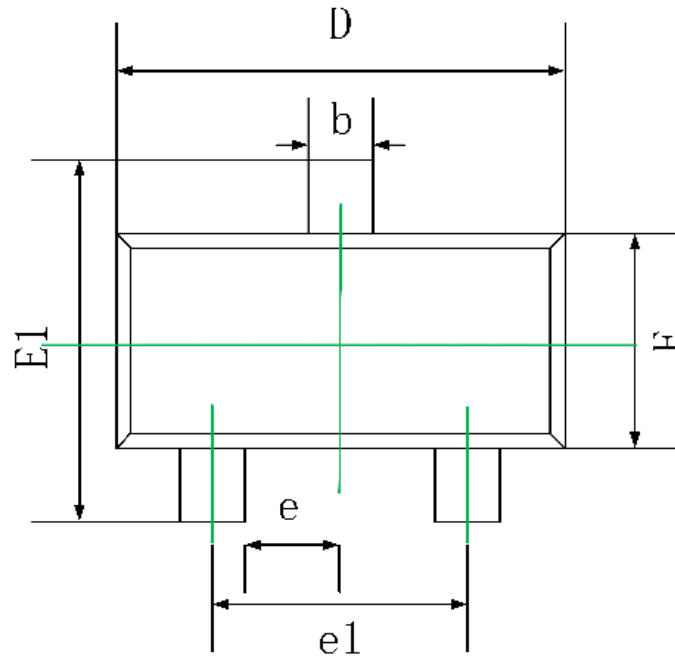


Figure8. Drain-Source Current

SOT-23 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.200	0.003	0.008
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020